



ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

May 12, 2026	
IGI Report Number	LG801607151
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	6.39 - 6.43 X 4.02 MM

GRADING RESULTS

Carat Weight	1.02 CARAT
Color Grade	E
Clarity Grade	VVS 2
Cut Grade	EXCELLENT

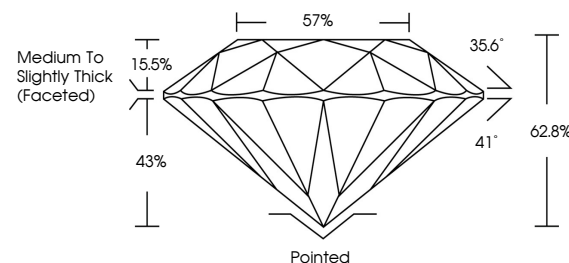
ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	 LG801607151

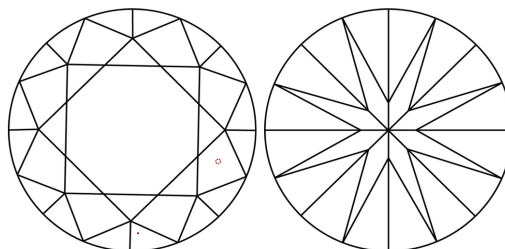
Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.
Type IIa

LG801607151
Report verification at igi.org

PROPORTIONS

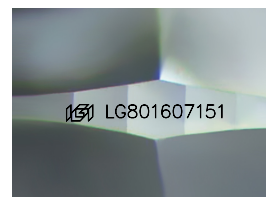


CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.



Sample Image Used

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

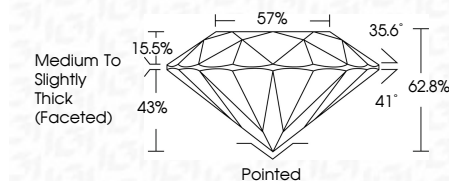
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www.igi.org

	VVS 2	E	1.02 CARAT
	EXCELLENT		
	62.8%		
	57%		
	Medium to Slightly Tuck (Focused)		
	Poished		
	EXCELLENT		
	EXCELLENT		NONE
			#GJL981607151

Comments:
The laboratory Grown Diamond was
found to have excellent vapor Deposition
and good growth process.